

# **SNx4HC14 Hex Inverters with Schmitt-Trigger Inputs**

#### 1 Features

- **Buffered inputs**
- Wide operating voltage range: 2V to 6V
- Wide operating temperature range: -40°C to +85°C
- Supports fanout up to 10 LSTTL loads
- Significant power reduction compared to LSTTL logic ICs

## 2 Applications

- Synchronize inverted clock inputs
- Debounce a switch
- Invert a digital signal

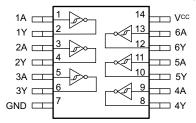
## 3 Description

This device contains six independent inverters with Schmitt-trigger inputs. Each gate performs the Boolean function  $Y = \overline{A}$  in positive logic.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE(2)	BODY SIZE(3)
	D (SOIC, 14)	8.65mm × 6mm	8.65mm × 3.9mm
	DB (SSOP, 14)	6.2 mm × 7.8mm	6.2mm × 5.30mm
SN74AHC14	N (PDIP, 14)	19.3mm × 9.4mm	19.3mm × 6.35mm
	NS (SOP, 14)	10.2mm x 7.8mm	10.3mm x 5.3mm
	PW (TSSOP, 14)	5mm × 6.4mm	5mm × 4.4mm
	J (CDIP, 14)	19.56mm × 7.9mm	19.56mm × 6.67mm
SN54AHC14	W (CFP, 14)	9.21mm x 9mm	9.21mm × 6.3mm
	FK (LCCC, 20)	8.9mm × 8.9mm	8.9mm × 8.9mm

- For more information, see Section 11.
- The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



**Functional pinout** 



## **Table of Contents**

1 Features	1 7.2 Functional Block Diagram	9
2 Applications	1 7.3 Feature Description	9
3 Description	1 7.4 Device Functional Modes	10
4 Pin Configuration and Functions	3 8 Application and Implementation	11
5 Specifications	4 8.1 Application Information	11
5.1 Absolute Maximum Ratings	4 8.2 Typical Application	11
5.2 ESD Ratings	4 8.3 Power Supply Recommendations	13
5.3 Recommended Operating Conditions	4 8.4 Layout	13
5.4 Thermal Information	4 9 Device and Documentation Support	14
5.5 Electrical Characteristics - 74	5 9.1 Documentation Support	14
5.6 Electrical Characteristics - 54	5 9.2 Support Resources	14
5.7 Switching Characteristics - 74	6 9.3 Trademarks	14
5.8 Switching Characteristics - 54	7 9.4 Electrostatic Discharge Caution	14
5.9 Operating Characteristics	7 9.5 Glossary	14
5.10 Typical Characteristics	7 10 Revision History	14
6 Parameter Measurement Information	8 11 Mechanical, Packaging, and Orderable	
7 Detailed Description	9 Information	14
7.1 Overview	9	



## **4 Pin Configuration and Functions**

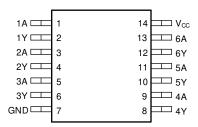


Figure 4-1. D, DB, N, NS, PW, J, or W Package 14-Pin SOIC, SSOP, PDIP, SO, TSSOP, CDIP, or CFP Top View

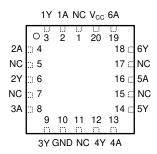


Figure 4-2. FK Package 20-Pin LCCC Top View

#### **Pin Functions**

	PIN			
NAME	D, DB, N, NS, PW, J, or W	FK	I/O	DESCRIPTION
1A	1	2	Input	Channel 1, Input A
1Y	2	3	Output	Channel 1, Output Y
2A	3	4	Input	Channel 2, Input A
2Y	4	6	Output	Channel 2, Output Y
3A	5	8	Input	Channel 3, Input A
3Y	6	9	Output	Channel 3, Output Y
GND	7	10	_	Ground
4Y	8	12	Output	Channel 4, Output Y
4A	9	13	Input	Channel 4, Input A
5Y	10	14	Output	Channel 5, Output Y
5A	11	16	Input	Channel 5, Input A
6Y	12	18	Output	Channel 6, Output Y
6A	13	19	Input	Channel 6, Input A
V <sub>CC</sub>	14	20	_	Positive Supply
NC		1, 5, 7, 11, 15, 17	_	Not internally connected



## **5 Specifications**

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$V_I < 0$ or $V_I > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	V <sub>O</sub> < 0		±20	mA
Io	Continuous output current	$V_{O} = 0$ to $V_{CC}$		±25	mA
	Continuous current through V <sub>CC</sub> or GND	·		±50	mA
TJ	Junction temperature <sup>(3)</sup>			150	°C
T <sub>stg</sub>	Storage temperature		-60	150	°C

- (1) Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) Guaranteed by design.

#### 5.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/ JEDEC JS-001 <sup>(1)</sup>	±2000	V
V(ESD)	Lieurostano disoriarge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

#### 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5	6	V
VI	Input voltage		0		$V_{CC}$	V
Vo	Output voltage		0		$V_{CC}$	V
_		54HC14	<b>–</b> 55		125	°C
T <sub>A</sub>	Operating free-air temperature	74HC14	-40		85	C

#### 5.4 Thermal Information

				SN74HC14			
	THERMAL METRIC(1)	D (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	133.6	114.8	60.7	122.6	151.7	°C/W
R <sub>θ</sub> JC(top)	Junction-to-case (top) thermal resistance	89	64.5	47.8	81.8	79.4	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	89.5	65.1	40.6	83.8	94.7	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	45.5	23.7	26.9	45.4	25.2	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	89.1	64.4	40.5	83.4	94.1	°C/W

Product Folder Links: SN54HC14 SN74HC14



			SN74HC14							
	THERMAL METRIC(1)	D (SOIC)	D (SOIC) DB (SSOP) N (PDIP) NS (SO) PW (TS							
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS				
R <sub>θ</sub> JC(bot)	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	°C/W			

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

#### 5.5 Electrical Characteristics - 74

over operating free-air temperature range; typical values measured at  $T_A$  = 25°C (unless otherwise noted).

			3 / 11		С	perating	free-air	temperat	ure (T <sub>A</sub> )		
ı	PARAMETER	TES	T CONDITIONS	V <sub>cc</sub>		25°C		-40°	C to 85°	С	UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
	Positive			2 V	0.7	1.2	1.5	0.7		1.5	
$V_{T+}$	switching			4.5 V	1.55	2.5	3.13	1.55		3.13	V
	threshold			6 V	2.1	3.3	4.2	2.1		4.2	
	Negative			2 V	0.3	0.6	1	0.3		1	
V <sub>T-</sub>	switching			4.5 V	0.9	1.6	2.45	0.9		2.45	V
	threshold			6 V	1.2	2	3.2	1.2		3.2	
				2 V	0.2	0.6	1.2	0.2		1.2	
$\Delta V_T$	Hysteresis (V <sub>T+</sub> - V <sub>T-</sub> )			4.5 V	0.4	0.9	2.1	0.4		2.1	V
	V 1-7			6 V	0.5	1.3	2.5	0.5		2.5	
				2 V	1.9	1.998		1.9			
			$I_{OH} = -20 \mu A$	4.5 V	4.4	4.499		4.4			
V <sub>OH</sub>	High-level output voltage	$V_I = V_{IH}$ or $V_{IL}$		6 V	5.9	5.999		5.9			V
	odiput voltage	OI VIL	I <sub>OH</sub> = -4 mA	4.5 V	3.98	4.3		3.84			
			I <sub>OH</sub> = -5.2 mA	6 V	5.48	5.8		5.34			
				2 V		0.002	0.1			0.1	
			I <sub>OL</sub> = 20 μA	4.5 V		0.001	0.1			0.1	
V <sub>OL</sub>	Low-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		6 V		0.001	0.1			0.1	V
	Voltage	OI VIL	I <sub>OL</sub> = 4 mA	4.5 V		0.17	0.26			0.33	
			I <sub>OL</sub> = 5.2 mA	6 V		0.15	0.26			0.33	
I	Input leakage current	V <sub>I</sub> = V <sub>CC</sub> o		6 V			±0.1			±1	μΑ
I <sub>CC</sub>	Supply current	V <sub>I</sub> = V <sub>CC</sub> or 0	I <sub>O</sub> = 0	6 V			2			20	μΑ
Ci	Input capacitance			5 V		3	10			10	pF

### 5.6 Electrical Characteristics - 54

over operating free-air temperature range; typical values measured at TA = 25°C (unless otherwise noted).

					Operating free-air temperature (T <sub>A</sub> )									
ı	PARAMETER	TEST CONDITIONS		V <sub>cc</sub>	25°C			–40°	°C to 85°	С	–55°0	C to 125	°C	UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
	Positive			2 V	0.7	1.2	1.5	0.7		1.5	0.7		1.5	
V <sub>T+</sub>	V <sub>T+</sub> switching			4.5 V	1.55	2.5	3.13	1.55		3.13	1.55		3.13	V
	threshold			6 V	2.1	3.3	4.2	2.1		4.2	2.1		4.2	



over operating free-air temperature range; typical values measured at TA = 25°C (unless otherwise noted).

			<u> </u>				Opera	ting free	-air temp	peratur	e (T <sub>A</sub> )			
ı	PARAMETER	TEST CO	NDITIONS	Vcc		25°C		-40°	°C to 85°	,C	-55°	C to 125	s°C	UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
	Negative			2 V	0.3	0.6	1	0.3		1	0.3		1	
V <sub>T-</sub>	switching			4.5 V	0.9	1.6	2.45	0.9		2.45	0.9		2.45	V
	threshold			6 V	1.2	2	3.2	1.2		3.2	1.2		3.2	
				2 V	0.2	0.6	1.2	0.2		1.2	0.2		1.2	
ΔV <sub>T</sub>	Hysteresis (V <sub>T+</sub> - V <sub>T-</sub> )			4.5 V	0.4	0.9	2.1	0.4		2.1	0.4		2.1	V
	V 1-/			6 V	0.5	1.3	2.5	0.5		2.5	0.5		2.5	
				2 V	1.9	1.998		1.9			1.9			
			I <sub>OH</sub> = –20 μΑ	4.5 V	4.4	4.499		4.4			4.4			
	High-level	V <sub>I</sub> = V <sub>IH</sub> or	μ, τ	6 V	5.9	5.999		5.9			5.9			
V <sub>OH</sub>	output voltage	V <sub>IL</sub>	I <sub>OH</sub> = -4 mA	4.5 V	3.98	4.3		3.84			3.7			V
			I <sub>OH</sub> = -5.2 mA	6 V	5.48	5.8		5.34			5.2			
				2 V		0.002	0.1			0.1			0.1	
			I <sub>OL</sub> = 20 μΑ	4.5 V		0.001	0.1			0.1			0.1	
V <sub>OL</sub>	Low-level output	$V_I = V_{IH}$ or	-	6 V		0.001	0.1			0.1			0.1	V
I OL	voltage	V <sub>IL</sub>	I <sub>OL</sub> = 4 mA	4.5 V		0.17	0.26			0.33			0.33	-
			I <sub>OL</sub> = 5.2 mA	6 V		0.15	0.26			0.33			0.33	
I	Input leakage current	V <sub>I</sub> = V <sub>CC</sub> or	0	6 V			±0.1			±1			±1	μA
I <sub>CC</sub>	Supply current	V <sub>I</sub> = V <sub>CC</sub> or 0	I <sub>O</sub> = 0	6 V			2			20			40	μA
Ci	Input capacitance			2 V to 6 V		3	10			10			10	pF

## 5.7 Switching Characteristics - 74

over operating free-air temperature range (unless otherwise noted)

					Op	erating	free-air	temperat	ure (T <sub>A</sub> )		
	PARAMETER		то	V <sub>cc</sub>	25°C			–40°	C to 85°	,C	UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
				2 V		55	125			155	
t <sub>pd</sub>	Propagation delay	Α	Υ	4.5 V		12	25			31	ns
				6 V		11	21			26	
				2 V		38	75			95	
t <sub>t</sub>	Transition-time		Υ	4.5 V		8	15			19	ns
				6 V		6	13			16	



## 5.8 Switching Characteristics - 54

over operating free-air temperature range; typical values measured at TA = 25°C (unless otherwise noted).

					Operating free-air temperature (T <sub>A</sub> )									
PARAMETER		FROM	то	V <sub>cc</sub>	25°C			-40°C to 85°C			-55°C	C to 12	5°C	UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
			2 V		55	125			155			190		
t <sub>pd</sub>	Propagation delay	A	Y	4.5 V		12	25			31			38	ns
				6 V		11	21			26			22	
	t Transition-time		Υ	2 V		38	75			95			110	
t <sub>t</sub>				4.5 V		8	15			19			22	ns
				6 V		6	13			16			19	

## **5.9 Operating Characteristics**

over operating free-air temperature range; typical values measured at  $T_A$  = 25°C (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	UNIT
(	Power dissipation capacitance per gate	No load	2 V to 6 V		20		pF

# **5.10 Typical Characteristics**

 $T_A = 25^{\circ}C$ 

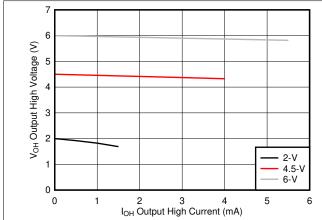


Figure 5-1. Typical output voltage in the high state  $(V_{OH})$ 

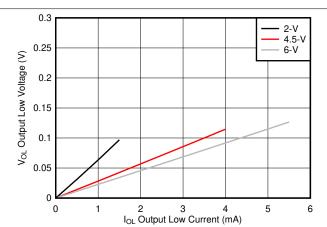
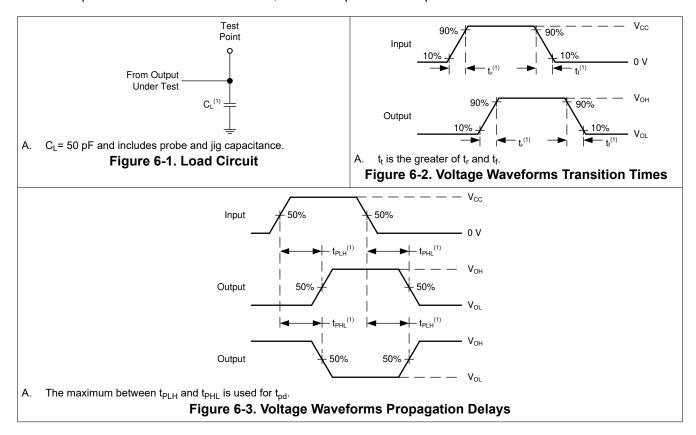


Figure 5-2. Typical output voltage in the low state  $(V_{OL})$ 



#### **6 Parameter Measurement Information**

- Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z<sub>O</sub> = 50 Ω, t<sub>t</sub> < 6 ns.</li>
- The outputs are measured one at a time, with one input transition per measurement.





## 7 Detailed Description

#### 7.1 Overview

This device contains six independent inverters with Schmitt-trigger inputs. Each gate performs the Boolean function  $Y = \overline{A}$  in positive logic.

## 7.2 Functional Block Diagram

### 7.3 Feature Description

#### 7.3.1 Balanced CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The drive capability of this device may create fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to over-current. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

The SN74HC14 can drive a load with a total capacitance less than or equal to the maximum load listed in the *Switching Characteristics* - 74 connected to a high-impedance CMOS input while still meeting all of the datasheet specifications. Larger capacitive loads can be applied, however it is not recommended to exceed the provided load value. If larger capacitive loads are required, it is recommended to add a series resistor between the output and the capacitor to limit output current to the values given in the *Absolute Maximum Ratings*.

#### 7.3.2 CMOS Schmitt-Trigger Inputs

Standard CMOS inputs are high impedance and are typically modeled as a resistor from the input to ground in parallel with the input capacitance given in the *Electrical Characteristics - 74*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics - 74*, using ohm's law  $(R = V \div I)$ .

The Schmitt-trigger input architecture provides hysteresis as defined by  $\Delta V_T$  in the *Electrical Cahracteristics* -74, which makes this device extremely tolerant to slow or noisy inputs. While the inputs can be driven much slower than standard CMOS inputs, it is still recommended to properly terminate unused inputs. Driving the inputs slowly will also increase dynamic current consumption of the device. For additional information regarding Schmitt-trigger inputs, please see Understanding Schmitt Triggers.

Copyright © 2025 Texas Instruments Incorporated

### 7.3.3 Clamp Diode Structure

The inputs and outputs to this device have both positive and negative clamping diodes as depicted in Figure 7-1.

#### **CAUTION**

Voltages beyond the values specified in the Absolute Maximum Ratings table can cause damage to the device. The recommended input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

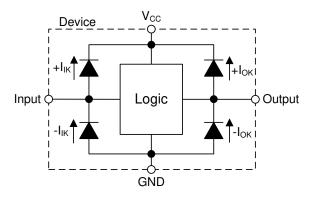


Figure 7-1. Electrical Placement of Clamping Diodes for Each Input and Output

### 7.4 Device Functional Modes

**Table 7-1. Function Table** 

INPUT	OUTPUT
Α	Υ
L	Н
Н	L

Submit Document Feedback

Copyright © 2025 Texas Instruments Incorporated



## 8 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

This device can be used to add an additional stage to a counter with an external flip-flop. Because counters use a negative edge trigger, the flip-flop's clock input must be inverted to provide this function. This function only requires one of the six available inverters in the device, so the remaining channels can be used for other applications needing an inverted signal or improved signal integrity. Unused inputs must be terminated at  $V_{CC}$  or GND. Unused outputs can be left floating.

#### 8.2 Typical Application

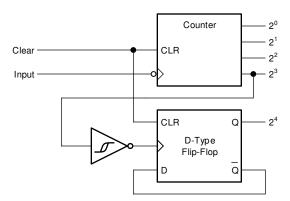


Figure 8-1. Typical application schematic

#### 8.2.1 Design Requirements

#### 8.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics - 74*.

The supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74HC14 plus the maximum supply current,  $I_{CC}$ , listed in the *Electrical Characteristics - 74*. The logic device can only source or sink as much current as it is provided at the supply and ground pins, respectively. Be sure not to exceed the maximum total current through GND or  $V_{CC}$  listed in the *Absolute Maximum Ratings*.

Total power consumption can be calculated using the information provided in CMOS Power Consumption and  $C_{\text{pd}}$  Calculation.

Thermal increase can be calculated using the information provided in Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices.

#### **CAUTION**

The maximum junction temperature,  $T_J(max)$  listed in the *Absolute Maximum Ratings*, is an *additional limitation* to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

#### 8.2.1.2 Input Considerations

Input signals must cross  $V_{t-}(min)$  to be considered a logic LOW, and  $V_{t+}(max)$  to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either  $V_{CC}$  or ground. These can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input is to be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The resistor size is limited by drive current of the controller, leakage current into the SN74HC14, as specified in the *Electrical Characteristics - 74*, and the desired input transition rate. A 10-k $\Omega$  resistor value is often used due to these factors.

The SN74HC14 has no input signal transition rate requirements because it has Schmitt-trigger inputs.

Another benefit to having Schmitt-trigger inputs is the ability to reject noise. Noise with a large enough amplitude can still cause issues. To know how much noise is too much, please refer to the  $\Delta V_T$ (min) in the *Electrical Characteristics* - 74. This hysteresis value will provide the peak-to-peak limit.

Unlike what happens with standard CMOS inputs, Schmitt-trigger inputs can be held at any valid value without causing huge increases in power consumption. The typical additional current caused by holding an input at a value other than V<sub>CC</sub> or ground is plotted in the *Typical Characteristics*.

Refer to the Feature Description for additional information regarding the inputs for this device.

#### 8.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the  $V_{OH}$  specification in the *Electrical Characteristics - 74*. Similarly, the ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the  $V_{OL}$  specification in the *Electrical Characteristics 74*.

Unused outputs can be left floating. Do not connect outputs directly to V<sub>CC</sub> or ground.

Refer to Feature Description for additional information regarding the outputs for this device.

#### 8.2.2 Detailed Design Procedure

- Add a decoupling capacitor from V<sub>CC</sub> to GND. The capacitor needs to be placed physically close to the
  device and electrically close to both the V<sub>CC</sub> and GND pins. An example layout is shown in the Layout.
- 2. Ensure the capacitive load at the output is ≤ 70 pF. This is not a hard limit, however it will ensure optimal performance. This can be accomplished by providing short, appropriately sized traces from the SN74HC14 to the receiving device.
- 3. Ensure the resistive load at the output is larger than  $(V_{CC} / I_O(max)) \Omega$ . This will ensure that the maximum output current from the *Absolute Maximum Ratings* is not violated. Most CMOS inputs have a resistive load measured in megaohms; much larger than the minimum calculated above.
- 4. Thermal issues are rarely a concern for logic gates, however the power consumption and thermal increase can be calculated using the steps provided in the application report, CMOS Power Consumption and Cpd Calculation

#### 8.2.3 Application Curves

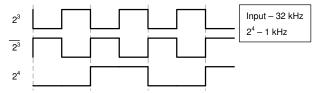


Figure 8-2. Typical application timing diagram

Submit Document Feedback

Copyright © 2025 Texas Instruments Incorporated



#### 8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in *Figure 8-3*.

## 8.4 Layout

#### 8.4.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

#### 8.4.2 Layout Example

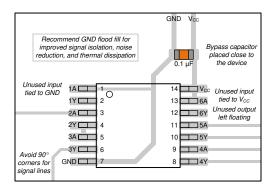


Figure 8-3. Example layout for the SN74HC14



## 9 Device and Documentation Support

#### 9.1 Documentation Support

#### 9.1.1 Related Documentation

For related documentation see the following:

- HCMOS Design Considerations
- CMOS Power Consumption and CPD Calculation
- Designing with Logic

#### 9.2 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 9.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

#### 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

C	changes from Revision K (June 2021) to Revision L (July 2024)	Page
•	Added package sizes to Device Information table	1
•	Updated thermal values for N package from ΨJB = 40.3 to 40.5, all values in °C/W	4
C	changes from Revision J (October 2016) to Revision K (June 2021)	Page
•	Updated the numbering format for tables, figures and cross-references throughout the document	1
•	Updated to new data sheet standards	1
•	Updated package sizing for DB package in Device Information table	1
•	Increased D (86 to 133.6), DB (96 to 114.8), NS (76 to 122.6), and PW (113 to 151.7); decreased N (	
		00.0
	60.7) °C/W	

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN54HC14 SN74HC14

www.ti.com

26-Sep-2025

## **PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
5962-8409101VCA	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8409101VC A SNV54HC14J
5962-8409101VCA.A	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8409101VC A SNV54HC14J
5962-8409101VDA	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8409101VD A SNV54HC14W
5962-8409101VDA.A	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8409101VD A SNV54HC14W
84091012A	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	84091012A SNJ54HC 14FK
8409101CA	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8409101CA SNJ54HC14J
8409101DA	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8409101DA SNJ54HC14W
JM38510/65702BCA	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65702BCA
JM38510/65702BCA.A	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65702BCA
JM38510/65702BDA	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65702BDA
JM38510/65702BDA.A	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65702BDA
M38510/65702BCA	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65702BCA
M38510/65702BDA	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65702BDA
SN54HC14J	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC14J
SN54HC14J.A	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC14J
SN74HC14D	Obsolete	Production	SOIC (D)   14	-	-	Call TI	Call TI	-40 to 85	HC14





26-Sep-2025 www.ti.com

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	(3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74HC14DBR	Active	Production	SSOP (DB)   14	2000   LARGE T&R	Yes	NIPDAU   NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14DBR.A	Active	Production	SSOP (DB)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14DR	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU   SN	NIPDAU   SN Level-1-260C-UNLIM		HC14
SN74HC14DR.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14DR.B	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14DRG3	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14DRG3.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14DRG4	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14DRG4.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14DRG4.B	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14DT	Obsolete	Production	SOIC (D)   14	-	-	Call TI	Call TI	-40 to 85	HC14
SN74HC14N	Active	Production	PDIP (N)   14	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC14N
SN74HC14N.A	Active	Production	PDIP (N)   14	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC14N
SN74HC14NE4	Active	Production	PDIP (N)   14	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC14N
SN74HC14NSR	Active	Production	SOP (NS)   14	2000   LARGE T&R	Yes	NIPDAU   NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14NSR.A	Active	Production	SOP (NS)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14NSR.B	Active	Production	SOP (NS)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14NSRE4	Active	Production	SOP (NS)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14PW	Obsolete	Production	TSSOP (PW)   14	-	-	Call TI	Call TI	-40 to 85	HC14
SN74HC14PWR	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14PWR.A	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14PWRG4	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14PWRG4.A	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC14
SN74HC14PWT	Obsolete	Production	TSSOP (PW)   14	-	-	Call TI	Call TI	-40 to 85	HC14
SNJ54HC14FK	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	84091012A SNJ54HC 14FK
SNJ54HC14FK.A	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	84091012A SNJ54HC 14FK
SNJ54HC14J	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8409101CA SNJ54HC14J

26-Sep-2025

SNJ54HC14W

www.ti.com

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
SNJ54HC14J.A	Active	Production	CDIP (J)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8409101CA SNJ54HC14J
SNJ54HC14W	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8409101DA SNJ54HC14W
SNJ54HC14W.A	Active	Production	CFP (W)   14	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8409101DA

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN54HC14, SN54HC14-SP, SN74HC14:

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



## **PACKAGE OPTION ADDENDUM**

www.ti.com 26-Sep-2025

● Catalog : SN74HC14, SN54HC14

• Automotive : SN74HC14-Q1, SN74HC14-Q1

Military: SN54HC14

• Space : SN54HC14-SP

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application



www.ti.com 17-Sep-2025

### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC14DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74HC14DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC14DRG3	SOIC	D	14	2500	330.0	16.4	6.6	9.3	2.1	8.0	16.0	Q1
SN74HC14DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC14NSR	SOP	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74HC14PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC14PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



www.ti.com 17-Sep-2025



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC14DBR	SSOP	DB	14	2000	353.0	353.0	32.0
SN74HC14DR	SOIC	D	14	2500	340.5	336.1	32.0
SN74HC14DRG3	SOIC	D	14	2500	366.0	364.0	50.0
SN74HC14DRG4	SOIC	D	14	2500	340.5	336.1	32.0
SN74HC14NSR	SOP	NS	14	2000	353.0	353.0	32.0
SN74HC14PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74HC14PWRG4	TSSOP	PW	14	2000	353.0	353.0	32.0



www.ti.com 17-Sep-2025

### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-8409101VDA	W	CFP	14	25	506.98	26.16	6220	NA
5962-8409101VDA.A	W	CFP	14	25	506.98	26.16	6220	NA
84091012A	FK	LCCC	20	55	506.98	12.06	2030	NA
8409101DA	W	CFP	14	25	506.98	26.16	6220	NA
JM38510/65702BDA	W	CFP	14	25	506.98	26.16	6220	NA
JM38510/65702BDA.A	W	CFP	14	25	506.98	26.16	6220	NA
M38510/65702BDA	W	CFP	14	25	506.98	26.16	6220	NA
SN74HC14N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HC14N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HC14N.A	N	PDIP	14	25	506	13.97	11230	4.32
SN74HC14N.A	N	PDIP	14	25	506	13.97	11230	4.32
SN74HC14NE4	N	PDIP	14	25	506	13.97	11230	4.32
SN74HC14NE4	N	PDIP	14	25	506	13.97	11230	4.32
SNJ54HC14FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC14FK.A	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC14W	W	CFP	14	25	506.98	26.16	6220	NA
SNJ54HC14W.A	W	CFP	14	25	506.98	26.16	6220	NA

# W (R-GDFP-F14)

## CERAMIC DUAL FLATPACK



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14







#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-150.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



**INSTRUMENTS** www.ti.com

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



#### NOTES:

- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
   Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
   Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



# N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.







#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025. Texas Instruments Incorporated